

# FERD30SM100DJF

### Datasheet

### 100 V, 30 A field effect rectifier



PowerFLAT™ 5x6 (non-contractual)

### **Features**

- ST patented rectifier process
- Stable leakage current over reverse voltage
- Low forward voltage drop
- High frequency operation
- ECOPACK<sup>®</sup>2 compliant

### **Applications**

- Switching diode
- Notebook adapter
- LED lighting
- DC / DC converter

### **Description**

The FERD30SM100DJF is based on a proprietary technology that achieves the best in class V<sub>F</sub> / I<sub>R</sub> trade-off for a given silicon surface.

Packaged in PowerFLAT<sup>™</sup> 5x6, the FERD30SM100DJF is optimized for use in confined applications where both efficiency and thermal performance are key.

Product status		
FERD30SM100DJF		
Product summary		
Symbol	Value	
I <sub>F(AV)</sub>	30 A	
V <sub>RRM</sub>	100 V	
T <sub>j(max.)</sub>	175 °C	
<b>V</b> <sub>F(typ.)</sub> 0.665 ∨		



### 1 Characteristics

# Table 1. Absolute ratings (limiting values at 25 °C, unless otherwise specified, anode terminals short circuited)

Symbol	Parameter	Value	Unit	
V <sub>RRM</sub>	Repetitive peak reverse voltage	100	V	
I <sub>F(RMS)</sub>	Forward rms current	45	Α	
I <sub>F(AV)</sub>	Average forward current, $\delta$ = 0.5, square wave	30	Α	
I <sub>FSM</sub>	Surge non repetitive forward current	180	А	
T <sub>stg</sub>	Storage temperature range	-65 to +175	°C	
Тј	Maximum operating junction temperature <sup>(1)</sup>			°C

1.  $(dP_{tot'}/dT_j) < (1/R_{th(j-a)})$  condition to avoid thermal runaway for a diode on its own heatsink.

#### Table 2. Thermal resistance parameter

Symbol	Parameter	Max. value	Unit
R <sub>th(j-c)</sub>	Junction to case	2.6	°C/W

For more information, please refer to the following application note :

AN5046 : Printed circuit board assembly recommendations for STMicroelectronics PowerFLAT™ packages

#### Table 3. Static electrical characteristics (anode terminals short-circuited)

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I <sub>R</sub> <sup>(1)</sup> Reverse leakage current	Reverse leakage current	T <sub>j</sub> = 25 °C	V <sub>R</sub> = V <sub>RRM</sub>	-	-	150	μA
		T <sub>j</sub> = 125 °C		-	8	16	
	T <sub>j</sub> = 125 °C	V <sub>R</sub> = 70 V	-	-	9	ШA	
V <sub>F</sub> <sup>(2)</sup> Forward volta		T <sub>j</sub> = 25 °C	I <sub>F</sub> = 5 A	-		0.480	V
	Forward voltage drop	T <sub>j</sub> = 125 °C		-	0.395	0.435	
		T <sub>j</sub> = 25 °C	I <sub>F</sub> = 10 A	-		0.595	
		T <sub>j</sub> = 125 °C		-	0.510	0.555	
		T <sub>j</sub> = 25 °C	– I <sub>F</sub> = 30 A	-		0.970	
		T <sub>j</sub> = 125 °C		-	0.665	0.735	

1. Pulse test:  $t_p = 5 ms$ ,  $\delta < 2\%$ 

2. Pulse test:  $t_p = 380 \ \mu s, \ \delta < 2\%$ 

To evaluate the conduction losses, use the following equation:

 $P = 0.562 \text{ x } I_{F(AV)} + 0.0057 \text{ x } I_{F}^{2}(RMS)$ 

For more information, please refer to the following application notes related to the power losses :

- AN604: Calculation of conduction losses in a power rectifier
- AN4021: Calculation of reverse losses on a power diode

### 1.1 Characteristics (curves)







Figure 4. Reverse leakage current versus reverse voltage applied (typical values)



Figure 6. Forward voltage drop versus forward current (typical values, anode terminals short circuited)







#### Figure 7. Thermal resistance junction to ambient versus copper surface under tab (typical values)

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# 2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: www.st.com. ECOPACK<sup>®</sup> is an ST trademark.

### 2.1 PowerFLAT<sup>™</sup> 5x6 package information

- Epoxy meets UL 94,V0
- Cooling method: by conduction (C)





Bottom view



Top view

Dimensions						
<b>D</b> -4	Millimeters			Inches (for reference only)		
Rei	Min.	Тур.	Max.	Min.	Тур.	Max.
A	0.80		1.00	0.031		0.039
A1	0.00		0.05	0.000		0.002
b	0.30		0.50	0.01		0.02
с		0.25			0.010	
D	4.80		5.40	0.189		0.212
D2	3.91		4.45	0.154		0.175
e		1.27			0.050	
E	5.90		6.35	0.232		0.250
E2	3.34		3.70	0.138		0.146
L	0.50		0.80	0.020		0.031
К	1.10		1.575	0.015		0.023
L1	0.05	0.15	0.25	0.002	0.006	0.009

#### Table 4. PowerFLAT™ 5x6 mechanical data

### Figure 9. PowerFLAT™ 5x6 recommended footprint (dimensions are in mm)





# **3** Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
FERD30SM100DJFTR	F30SM 100	PowerFLAT™ 5x6	95 mg	3000	Tape and reel

Table 5. Ordering information

## **Revision history**

Date	Version	Changes
09-Jan-2015	1	Initial release.
29-Nov-2018	2	Updated Section Cover image and Section 2.1 PowerFLAT™ 5x6 package information. Added Section Applications.
08-Feb-2019	3	Updated Figure 8. PowerFLAT <sup>™</sup> 5x6 package outline (non-contractual) and Table 4. PowerFLAT <sup>™</sup> 5x6 mechanical data.

#### Table 6. Document revision history



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